PCN Number:		201	20170510000 PCN Date: May 11 201					11 2017						
Title: Qualification of select Devices			Amk	or an	d TI Cla	ark as a	an a	dditional Ass	em	ibly	and Test Sit	tes an	d for	
Cust	omer	•	PCN A	Manag	er		Dept:		Quality Ser	vic	es			
	osed	1 st Ship		Aug	11 2	017	Est	ima	ted Sample	A۱	/aila	allaniiitv.		ided upon Jest
	ige T	уре:					•							
\boxtimes		mbly Site			As	sembly	/ Proces	SS			\times	Assembly	Mater	ials
	Desi	gn			Ele	ectrical	Specif	icati	on			Mechanical Specification		
\boxtimes	Test	Site			Pa	cking/s	Shippin	g/La	abeling			Test Process		
	Wafe	er Bump Si	ite		W	Wafer Bump Material				Wafer Bump Process				
	Wafe	er Fab Site			W	afer Fa	b Mate	rials				Wafer Fab	Proce	ess
					Pa	rt num	ber cha	ange	2					
							PCN D)eta	ails					
Desc	riptio	on of Cha	nge:											
		and Test s							ition of Amko					
		What				PS			TI Clark		Amkor			
		Mold Con		d	9	SID#20			4208625		SI	D#101384		
		Lead finis				Matte			NiPdAu			Matte Sn		
		Bond Wir	e, Dia	mete	er /	Au, 1.0	mils		Au, 1.0 mils		(Cu, 0.96 Mils		
the C	SD58								ions in a sing I NiPdAu/Ag.	le	<u>staı</u>	ndard part	num	<u>ber</u> , for
Exam	iple:	– Custor Quanti				00units	of CSI)588	388Q5D with	25	500 ı	units SPQ (S	Standa	ard Pack
 TI can satisfy the above order in one of the following ways. I. 3 Reels of NiPdAu finish. II. 3 Reels of Matte Sn finish III. 2 Reels of Matte Sn and 1 reel of NiPdAu finish. IV. 2 Reels of NiPdAu and 1 reel of Matte Sn finish. 														
Test of MQ.	Test coverage, insertions, conditions will remain consistent with current testing and verified with test MQ.													
Reason for Change:														
Continuity of Supply														
Antic	Anticipated impact on Fit, Form, Function, Quality or Reliability (positive / negative):													
None														
Antic		ed impact												
the Material Declaration			produ Upon	aterial Declarations or Product Content reports are driven from roduction data and will be available following the production release pon production release the revised reports can be obtained from the <u>I ECO website</u> .				n release.						

Changes to product identification resulting from this PCN:

Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (21L)	Assembly City
PSI	PAC	PHL	Taguig City
TI Clark	QAB	PHL	Angeles City
Amkor	AP3	PHL	Binan

Sample product shipping label (not actual product label)





(1P) \$N74L\$07N\$R (Q) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY(1T) 7523483812 (P) (2P) REV: (V) 0033317 (2DL) CSO: SHE (21L) CCO: USA (22L) ASO: MLA (23L) ACO: MYS

Topside Device marking (if included):

Assembly site code for PAC= E
Assembly site code for QAB = I
Assembly site code for AP3 = 3

Product Affected

Group 1 Device list: Current AT site = PSi & Clark, Additional AT site = Amkor

Group 2 Device list: Current AT site= PSi, Additional AT site = Amkor

CSD17575Q3	CSD18532NQ5B	CSD19502Q5B	SN1607042Q5B
CSD17575Q3T	CSD18532NQ5BT	CSD19502Q5BT	

Group 3 Device list: Current AT site = PSi, Additional AT site = TI Clark

CSD58888Q5D



Qualification Report

Phase 7 Power Block Qual in Amkor P3: CSD87333Q3D, CSD87334Q3D, CSD87335Q3D Approve Date 06-February-2017

Product Attributes

Attributes	Qual Device: CSD87333Q3D	Qual Device: CSD87334Q3D	Qual Device: CSD87335Q3D
Assembly Site	AMKOR P3 A/T PHIL	AMKOR P3 A/T PHIL	AMKOR P3 A/T PHIL
Package Family	DQZ	DQZ	DQZ
Flammability Rating	UL 94 V-0	UL 94 V-0	UL 94 V-0
Wafer Fab Supplier	CFAB	CFAB	CFAB
Wafer Fab Process	NEXFET-LV 30N10	NEXFET-LV 30N10	NEXFET-LV 30N10

- QBS: Qual By Similarity
- Qual Device CSD87333Q3D is qualified at LEVEL1-260C
- Qual Device CSD87335Q3D is qualified at LEVEL1-260C
- Qual Device CSD87334Q3D is qualified at LEVEL1-260C
- Device CSD87333Q3D contains multiple dies.
- Device CSD87334Q3D contains multiple dies.
- Device CSD87335Q3D contains multiple dies.

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: CSD87333Q3D	Qual Device: CSD87334Q3D	Qual Device: CSD87335Q3D
MQ	Manufacturability (Assembly)	(per mfg. Site specification)	3/1/0 - Pass	3/1/0 - Pass	3/1/0 - Pass
PC	Preconditioning	(per the appropriate pkg level)	-	3/462/0	3/462/0
TC	**T/C -40C/125C	-40C/+125C (500,1000 Cycles)	-	3/231/0	3/231/0
TC	**T/C -55C/125C	-55C/+125C (500,1000 Cycles)	_	3/231/0	3/231/0

^{**} Preconditioning was performed for Temperature Cycle as applicable

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

⁻ The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles



5x6 QFN Q5D Power Block Qualification Summary

NCH MOSFET - Gen 2.0 30-10

	C SD87353Q5D Qualification Test Summary					
Stress	Conditions	Test Duration	Sample Size	Results		
HTRB	150°C/80% Rated Vds	1K hrs	3 lots x 77 units	Pass		
HTGB	150°C/80% Rated Vgs	1K hrs	3 lots x 77 units	Pass		
ТНВ	85°C/85%R.H./80% Rated Vds	1K hrs	3 lots x 77 units	Pass		
Autoclave	121C/100% RH	96 hrs	3 lots x 77 units	Pass		
Intermittent Op Life	Delta Tj = 100°C 2 min on/2 min off	10K cycles	3 lots x 77 units	Pass		
Temp Cycle	-40°C to 125°C	1K cycles	3 lots x 77 units	Pass		

Pass = 0/77 x 3 lots

MSL1 preconditioning performed on devices prior to THB, Autoclave, & Temp Cycle stresses

- External Visual @ 40X
- Temp Cycle: -40°C to +60°C, 5 cycles, 10 min dwell
- Bake: 24 hours @ 125°C
- Damp Heat: 168 hours @ 85°C/85% RH (Level 1)
- 3X reflow + flux + rinse, 260°C Pb free reflow temp

Original full qualification on CSD87353Q5D was run at PSi (above table). Clark assembly site is qualified by similarity since full qualification of 3 lots on CSD87350Q5D and full qualification of 1 lot on CSD87353Q5D was performed at Clark.

	C SD87353Q5D Qualification Test Summary				
Stress	Conditions	Test Duration	Sample Size	Results	
HTRB	150°C/80% Rated Vds	1K hrs	1 lot x 77 units	Pass	
HTGB	150°C/80% Rated Vgs	1K hrs	1 lot x 77 units	Pass	
THB	85°C/85%R.H./80% Rated Vds	1K hrs	1 lot x 77 units	Pass	
Autoclave	121C/100% RH	96 hrs	1 lot x 77 units	Pass	
Intermittent Op Life	Delta Tj = 100°C 2 min on/2 min off	10K cycles	1 lot x 77 units	Pass	
Temp Cycle	-40°C to 125°C	1K cycles	1 lot x 77 units	Pass	

TI Information - Selective Disclosure

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
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